WNSC5D04650T



# Silicon Carbide Diode

Rev.01 - 10 October 2022

**Product data sheet** 

### **1. General description**

Silicon Carbide Schottky diode in a DFN 8\*8 plastic package, designed for high frequency switched-mode power supplies.



### 2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

### 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

### 4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
$V_{\text{RRM}}$	RRM repetitive peak reverse 650 650				V		
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>c</sub> ≤ 149 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		4		А	
Tj	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min Typ Max		Unit	
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
Dynamic	characteristics	·					
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s}; V_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$		-	6	-	nC

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	[]	к <del>. К.</del> А
2	n.c.	not connected	5	001aaa020
3	A	anode		
4	А	anode		
5	К	mounting base; connected to cathode	1 2 3 4	

# 6. Ordering information

Table 3. Ordering information									
Type number	Package	Orderable part number	Packing	Small packing	Package	Package			
	name		method	quantity	version	issue date			
WNSC5D04650T	DFN8*8	WNSC5D04650T6J	Таре	3000	DFN8X8N	25-Dec-2019			

### 7. Marking

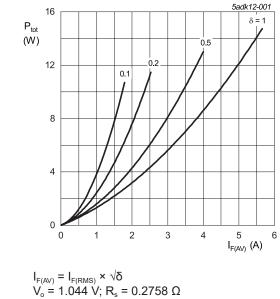
Table 4. Marking codes							
Type number	Marking codes						
WNSC5D04650T	WNSC5D 04650T						

# 8. Limiting values

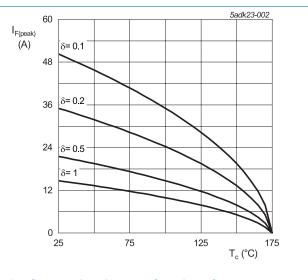
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage			650	V
V <sub>RWM</sub>	crest working reverse voltage			650	V
V <sub>R</sub>	reverse voltage	DC		650	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; square-wave pulse; T <sub>c</sub> ≤ 149 °C; Fig. 1; Fig. 2; Fig. 3		4	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>c</sub> ≤ 149 °C; square-wave pulse		8	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		28	А
	forward current	$t_p = 10 \ \mu s; T_{j(init)} = 25 \ ^{\circ}C; square-wave pulse$		290	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms		3.92	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature			-55 to 175	°C
Tj	junction temperature			-55 to 175	°C

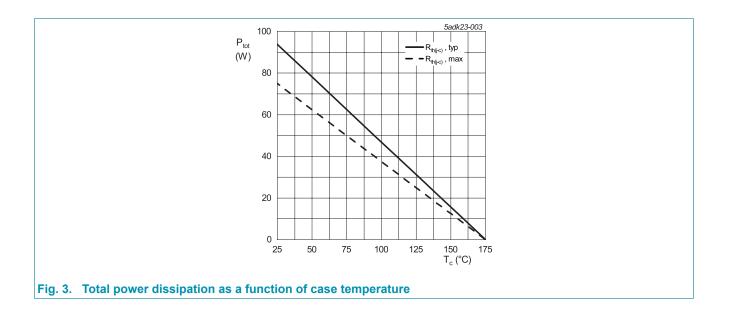


V<sub>o</sub> = 1.044 V; R<sub>s</sub> = 0.2758 Ω
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



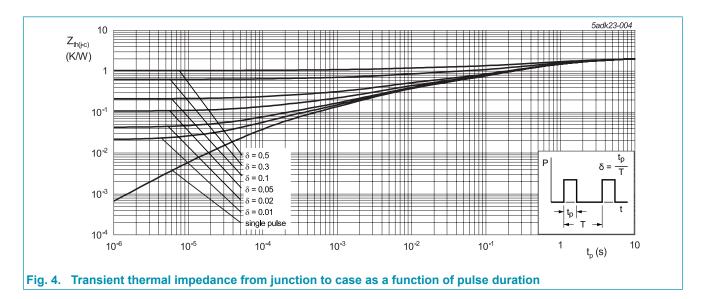


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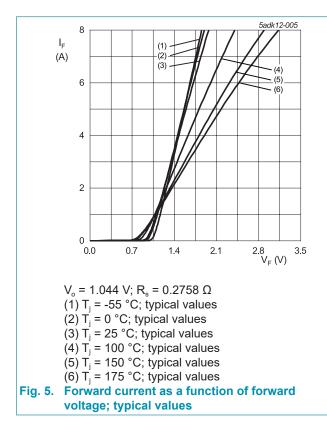
## 9. Thermal characteristics

Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	Fig. 4		-	1.6	2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W



## **10. Characteristics**

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
V <sub>F</sub>	forward current	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>		-	2.00	2.30	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	0.2	20	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>		-	10	100	μA
Dynamic	characteristics				-		
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}; V_R = 400 \text{ V}; \text{ d}_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$		-	6	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	138	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	17	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	15	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 2.8 A; L = 5 mH; T <sub>j(init)</sub> = 25 °C		20	-	-	mJ



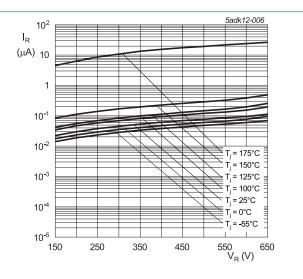
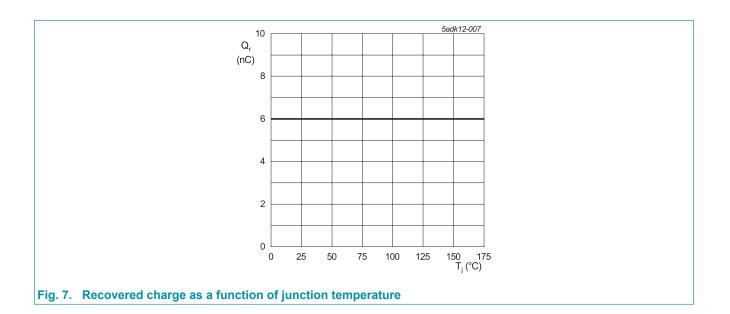
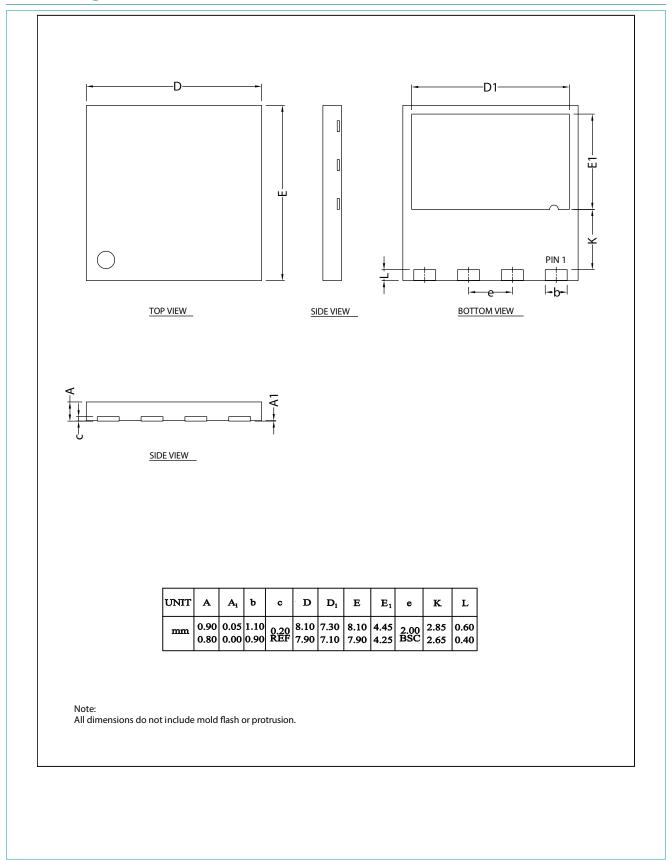


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

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# 11. Package outline



# WNSC5D04650T

#### Silicon Carbide Diode

# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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